Electronic Supplementary Information for

Defect energetics in high-entropy alloy fcc CoCrFeMnNi

Chan Gao^{a,*}, Shuyu Wang^a, Xiao Liu^a, Chandra Veer Singh^{b,c,*}

^aInstitute of Nuclear Physics and Chemistry, China Academy of Engineering Physics, Mianyang 621900, China

^bDepartment of Materials Science and Engineering, University of Toronto, Toronto, ON M5S 3E4, Canada ^cDepartment of Mechanical and Industrial Engineering, University of Toronto, Toronto, ON M5S 3G8, Canada

* Correspondence and request for materials should be addressed to Chan Gao (gaochan@caep.cn) and C.V. Singh (chandraveer.singh@utoronto.ca).

1. Chemical potentials for vacancy formation energy

In a crystal solid, a vacancy in a defective supercell with (N-1) atoms is created by removing an atom from a reference supercell with N atoms. Vacancy formation energy E_V^f given by:

$$E_V^f = E_d - E_0 + \mu \tag{1.1}$$

where E_d is the total energy of the defective supercell, E_0 is the total energy of the defect-free supercell, and μ is the chemical potential of the removed atom.

In the high-entropy alloys (HEAs), the vacancy formation energy $E_{V,j,k}^{f}$ for the atom of the type *j* with the atomic site index *k* removed for vacancy creation, given by:

$$E_{V,j,k}^{\ f} = E_{d,j,k} - E_0 + \mu_{j,k} \tag{1.2}$$

where $E_{d,j,k}$ is the total energy of the defective supercell that is the atom of the type *j* with the atomic site index *k* removed, and $\mu_{j,k}$ is the chemical potential of the atom of the type *j* with the atomic site index *k*.

Summing all $E_{V,j,k}^{f}$ from Eq. (1.2) over the atomic site index *k* with the same type *j* gives:

$$\sum_{k=1}^{N_j} E_{V,j,k}^{\ f} = \sum_{k=1}^{N_j} E_{d,j,k} - \sum_{k=1}^{N_j} E_0 + \sum_{k=1}^{N_j} \mu_{j,k}$$
(1.3)

where N_j is the number of the atomic site index k with the same type j. With sufficient

statistics,
$$\sum_{k=1}^{N_j} E_{V,j,k}^{f} = N_j < E_V^f >$$
, where $< E_V^f >$ is the mean vacancy formation
energy which should be independent of the specific atom removed. Assuming the
chemical potentials of atomic type *j* with different atomic site index *k* are the same,
rewriting Eq. (1.3) gives:

$$N_{j} < E_{V}^{f} > = \sum_{k=1}^{N_{j}} E_{d,j,k} - N_{j}E_{0} + N_{j}\mu_{j}$$
(1.3')

Then, this gives:

$$\mu_j = E_0 + \langle E_V^f \rangle - \frac{1}{N_j} \sum_{k=1}^{N_j} E_{d,j,k}$$
(1.4)

Continuing to sum all $E_{V,j,k}^{f}$ from Eq. (1.3) over the type *j* gives:

$$\sum_{j=1}^{M} \sum_{k=1}^{N_j} E_{V,j,k}^{f} = \sum_{j=1}^{M} \sum_{k=1}^{N_j} E_{d,j,k} - \sum_{j=1}^{M} \sum_{k=1}^{N_j} E_0 + \sum_{j=1}^{M} \sum_{k=1}^{N_j} \mu_{j,k}$$
(1.5)
$$\sum_{k=1}^{M} \sum_{j=1}^{N_j} \mu_{j,k} = E_0$$

where *M* is the number of atomic type *j*. Using j = 1k = 1, Eq. (1.5) becomes:

$$N < E_V^f >= \sum_{n=1}^N E_{d,n} - NE_0 + E_0$$
(1.5')

where N is the total number of the atoms in the perfect supercell, and $E_{d,n}$ is the total energy of the defective supercell irrespective of the type of the atom removed. Thus, Eq. (1.5') gives:

$$< E_V^f >= \frac{1}{N} \sum_{n=1}^N E_{d,n} - \frac{N-1}{N} E_0$$
 (1.6)

With the $\langle E_V^f \rangle$ calculated from Eq. (1.6), the chemical potential for each component can be obtained using Eq. (1.4). Then the vacancy formation energy $E_{V,j,k}^f$ can be obtained from Eq. (1.2). Finally the distribution of E_V^f can be obtained.

2. Chemical potentials for interstitial formation energy

In a crystal solid, an interstitial atom in a defective supercell with (N+1) atoms is created by adding an atom to a reference supercell with N atoms. Interstitial formation energy E_V^f given by:

$$E_V^f = E_d - E_0 - \mu$$
 (2.1)

where E_d is the total energy of the defective supercell, E_0 is the total energy of the defect-free supercell, and μ is the chemical potential of the added atom.

In the high-entropy alloys (HEAs), the interstitial formation energy $E_{I,j,k}^{f}$ for the

atom of the type j with the atomic site index k added for interstitial creation, given by:

$$E_{I,j,k}^{\ f} = E_{d,j,k} - E_0 - \mu_{j,k}$$
(2.2)

where $E_{d,j,k}$ is the total energy of the defective supercell that is the atom of the type *j* with the atomic site index *k* added, and $\mu_{j,k}$ is the chemical potential of the atom of the type *j* with the atomic site index *k*.

Summing all $E_{I,j,k}^{f}$ from Eq. (2.2) over the atomic site index k with the same type j gives:

$$\sum_{k=1}^{N_j} E_{I,j,k}^{f} = \sum_{k=1}^{N_j} E_{d,j,k} - \sum_{k=1}^{N_j} E_0 - \sum_{k=1}^{N_j} \mu_{j,k}$$
(2.3)

where N_j is the number of the atomic site index k with the same type j. With sufficient

 $\sum_{k=1}^{N_j} E_{I,j,k}^{f} = N_j < E_I^f >$, where $< E_I^f >$ is the mean interstitial formation energy which should be independent of the specific atom added. Assuming the chemical potentials of atomic type *j* with different atomic site index *k* are the same, rewriting Eq. (2.3) gives:

$$N_{j} < E_{I}^{f} >= \sum_{k=1}^{N_{j}} E_{d,j,k} - N_{j}E_{0} - N_{j}\mu_{j}$$
(2.3')

Then, this gives:

$$\mu_j = \frac{1}{N_j} \sum_{k=1}^{N_j} E_{d,j,k} - E_0 - \langle E_I^f \rangle$$
(2.4)

Continuing to sum all $E_{I,j,k}^{f}$ from Eq. (2.3) over the type *j* gives:

$$\sum_{j=1}^{M} \sum_{k=1}^{N_j} E_{l,j,k}^{f} = \sum_{j=1}^{M} \sum_{k=1}^{N_j} E_{d,j,k} - \sum_{j=1}^{M} \sum_{k=1}^{N_j} E_0 - \sum_{j=1}^{M} \sum_{k=1}^{N_j} \mu_{j,k}$$
(2.5)
$$\sum_{k=1}^{M} \sum_{j=1}^{N_j} \mu_{j,k} = E_0$$

where *M* is the number of atomic type *j*. Using j = 1k = 1, Eq. (2.5) becomes:

$$N < E_I^f >= \sum_{n=1}^N E_{d,n} - NE_0 - E_0$$
(2.5')

where N is the total number of the atoms in the perfect supercell, and $E_{d,n}$ is the total energy of the defective supercell irrespective of the type of the atom added. Thus, Eq. (2.5') gives:

$$< E_I^f > = \frac{1}{N} \sum_{n=1}^N E_{d,n} - \frac{N+1}{N} E_0$$
 (2.6)

With the $\langle E_I^f \rangle$ calculated from Eq. (2.6), the chemical potential for each component can be obtained using Eq. (2.4). Then the interstitial formation energy $E_{I,j,k}^{f}$ can be obtained from Eq. (2.2). Finally the distribution of E_I^f can be obtained.



Fig. S1. (a) Co interstitial formation energy for [100] Co-Co, Co-Cr, Co-Fe, Co-Mn, Co-Ni dumbbell in fcc CoCrFeMnNi HEA. There are 25 different calculations for each dumbbell and these data are compiled in an ascending order. (b) Total distribution of Co interstitial formation energies of all 125 samples in fcc CoCrFeMnNi HEA. The blue line represents Gaussian function fit.



Fig. S2. (a) Cr interstitial formation energy for [100] Cr-Co, Cr-Cr, Cr-Fe, Cr-Mn, Cr-Ni dumbbell in fcc CoCrFeMnNi HEA. There are 25 different calculations for each dumbbell and these data are compiled in an ascending order. (b) Total distribution of Cr interstitial formation energies of all 125 samples in fcc CoCrFeMnNi HEA. The blue line represents Gaussian function fit.



Fig. S3. (a) Fe interstitial formation energy for [100] Fe-Co, Fe-Cr, Fe-Fe, Fe-Mn, Fe-Ni dumbbell in fcc CoCrFeMnNi HEA. There are 25 different calculations for each dumbbell and these data are compiled in an ascending order. (b) Total distribution of Fe interstitial formation energies of all 125 samples in fcc CoCrFeMnNi HEA. The blue line represents Gaussian function fit.



Fig. S4. (a) Mn interstitial formation energy for [100] Mn-Co, Mn-Cr, Mn-Fe, Mn-Mn, Mn-Ni dumbbell in fcc CoCrFeMnNi HEA. There are 25 different calculations for each dumbbell and these data are compiled in an ascending order. (b) Total distribution of Mn interstitial formation energies of all 125 samples in fcc CoCrFeMnNi HEA. The blue line represents Gaussian function fit.



Fig. S5. Evolution of Co interstitial formation energy with the number of X atoms in the first nearest neighbor (1NN) in fcc CoCrFeMnNi HEA: (a) Co, (b) Cr, (c) Fe, (d) Mn, (e) Ni.



Fig. S6. Evolution of Cr interstitial formation energy with the number of X atoms in the first nearest neighbor (1NN) in fcc CoCrFeMnNi HEA: (a) Co, (b) Cr, (c) Fe, (d) Mn, (e) Ni.



Fig. S7. Evolution of Fe interstitial formation energy with the number of X atoms in the first nearest neighbor (1NN) in fcc CoCrFeMnNi HEA: (a) Co, (b) Cr, (c) Fe, (d) Mn, (e) Ni.



Fig. S8. Evolution of Mn interstitial formation energy with the number of X atoms in the first nearest neighbor (1NN) in fcc CoCrFeMnNi HEA: (a) Co, (b) Cr, (c) Fe, (d) Mn, (e) Ni.



Fig. S9. Energy landscape of vacancy migration in pure Ni.